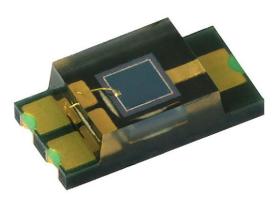
# VEMD6060X01

**Vishay Semiconductors** 





#### DESCRIPTION

VEMD6060X01 is a high speed and high sensitive PIN photodiode with excellent  $I_{ra}$  linearity. It is a small surface mount device (SMD) including the chip with a 0.85 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

- FEATURES
- Package type: surface mount
- Package form: 1206
- Dimensions (L x W x H in mm): 4 x 2 x 1.05
- Radiant sensitive area (in mm<sup>2</sup>): 0.85
- High photo sensitivity
- High radiant sensitivity
- Excellent Ira linearity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 70^{\circ}$
- Floor life: 72 h, MSL 4, according to J-STD-020
- Lead (Pb)-free reflow soldering
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- High speed photo detector
- Small signal detection
- Proximity sensors

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μΑ)	φ <b>(deg)</b>	λ <sub>0.1</sub> (nm)	
VEMD6060X01	5	± 70	380 to 1070	

#### Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD6060X01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	1206		

Note

• MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	20	V
Power dissipation	T <sub>amb</sub> ≤ 25 °C	Pv	215	mW
Junction temperature		Tj	110	°C
Operating temperature range		T <sub>amb</sub>	-40 to +110	°C
Storage temperature range		T <sub>stg</sub>	-40 to +110	°C
Soldering temperature	According to reflow solder profile fig. 8	T <sub>sd</sub>	260	°C
Thermal resistance junction / ambient	According to EIA / JESD51	R <sub>thJA</sub>	270	K/W

Rev. 1.0, 14-Jan-16

1 For technical questions, contact: <u>detectortechsupport@vishay.com</u> Document Number: 84296





COMPLIANT

HALOGEN

FREE GREEN

(5-2008)



www.vishay.com

## **Vishay Semiconductors**

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	0.85	1.1	V
Breakdown voltage	I <sub>R</sub> = 100 μA, E = 0	V <sub>(BR)</sub>	20	-	-	V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>	-	0.03	5	nA
Diode capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	CD	-	11	-	pF
	V <sub>R</sub> = 5 V, f = 1 MHz, E = 0	CD	-	4.8	-	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	Vo	-	360	-	mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	TK <sub>Vo</sub>	-	-3.1	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$	l <sub>k</sub>	-	5	-	μA
Temperature coefficient of $I_k$	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 835 \text{ nm}$	TK <sub>lk</sub>	-	0.1	-	%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	3.5	5	6.5	μA
	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 890 \text{ nm}$ , $V_R = 5 \text{ V}$	I <sub>ra</sub>	-	7	-	μA
Angle of half sensitivity		φ	-	± 70	-	deg
Wavelength of peak sensitivity		λρ	-	820	-	nm
Range of spectral bandwidth		λ <sub>0.1</sub>	-	380 to 1070	-	nm
Rise time	$V_R$ = 10 V, $R_L$ = 50 $\Omega$ , $\lambda$ = 830 nm	t <sub>r</sub>	-	60	-	ns
Fall time	$V_R$ = 10 V, $R_L$ = 50 $\Omega$ , $\lambda$ = 830 nm	t <sub>f</sub>	-	50	-	ns

#### **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

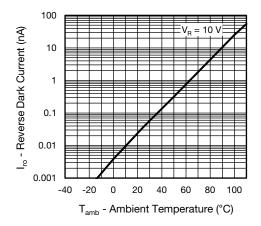


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

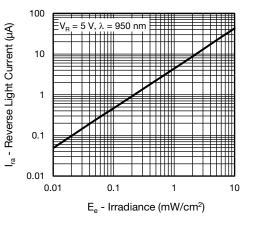
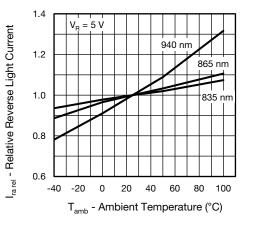
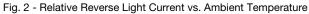


Fig. 3 - Reverse Light Current vs. Irradiance





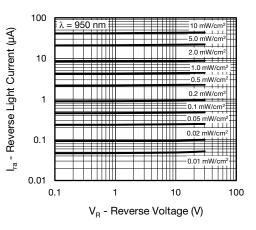


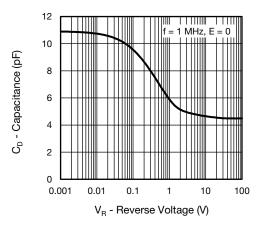
Fig. 4 - Reverse Light Current vs. Reverse Voltage

Document Number: 84296

For technical questions, contact: <u>detectortechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



## **Vishay Semiconductors**



www.vishay.com

Fig. 5 - Diode Capacitance vs. Reverse Voltage

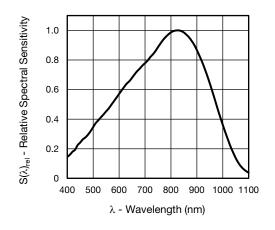


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

#### **REFLOW SOLDER PROFILE**

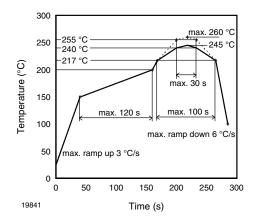


Fig. 8 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

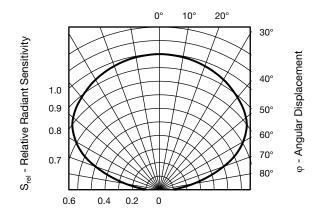


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 72 h

Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

Moisture sensitivity level 4, according to J-STD-020.

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

3

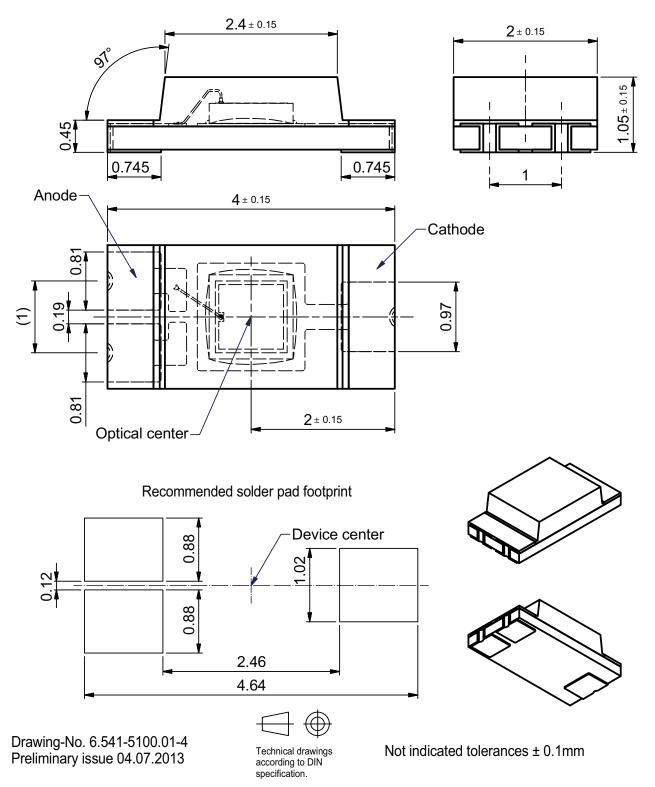
For technical questions, contact: <u>detectortechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



VISHAY, www.vishay.com

### **PACKAGE DIMENSIONS** in millimeters

Vishay Semiconductors



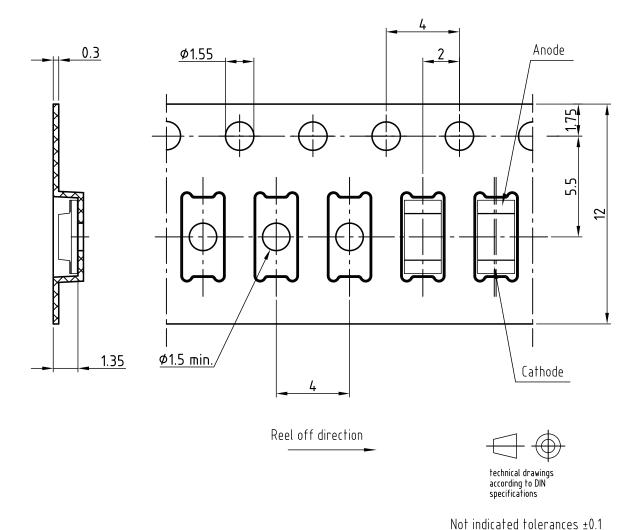
4 For technical questions, contact: <u>detectortechsupport@vishay.com</u>

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



**Vishay Semiconductors** 

#### **BLISTER TAPE DIMENSIONS** in millimeters



 Drawing refers to following Types:
 TEMD6010FX01

 VEMD6x10X01
 VEMD6x10X01

 Drawing-No.:
 9.700-5329.02-4
 VEMD6x15X01

 Prel Issue:
 16.07.2013
 VEMD6x15X01

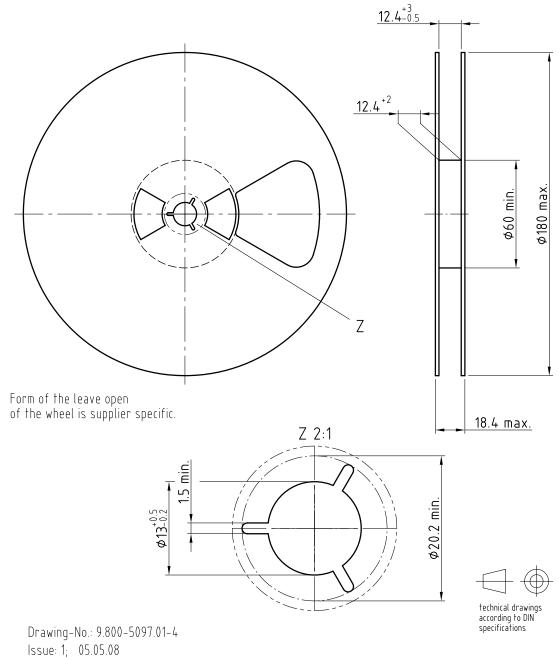
All dimensions in mm



Vishay Semiconductors



#### **REEL DIMENSIONS** in millimeters



20874

6



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2024 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

Revision: 01-Jul-2024